NSN 5961-01-203-5814

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-203-5814 **Inclosure Material:** Metal **Overall Length:** 1.646 inches **End Application:** Ssupply class aoe; emory s. Land class as; tarawa class lha; wasp class lhd; arleigh burke class ddg; kidd class ddg; nimitz class cvn; forrestal class cv; spruance class dd (963); landing system automatic carrier, dual channel **Mounting Facility Quantity:** 1 **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.562 inches **Thread Size:** 0.250 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1440.0 nonrepetitive peak reverse voltage and 1200.0 repetitive peak reverse voltage and 1200.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 35.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector universal and 60.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Weapon system essential **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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